Notice of References Cited

Application/Control No. 10/708,715		Applicant(s)/Patent Under Reexamination BARD ET AL.		
	Examiner	Art Unit		
	Sun J. Lin	2825	Page 1 of 2	

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-2003/0182640 A1	09-2003	Alani et al.	716/4
	В	US-			
	С	US-			
	D	US-			
	Ε	US-			
	F	US-			
	G	US-			
	Н	US-			
	1	US-			
	J	US-			
	К	US-			
	L	US-			
	М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	Р					
	Q					
	R					
	s					
	Т					

NON-PATENT DOCUMENTS

* Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)				
	U	Karlsson et al.,"Analytical Extraction Method for Submicron MOS Transistor Model Parameters in the Linear Region", Dec. 1994, IEEE Proceedings on Circuits, Devices and Systems, vol. 141, iss. 6, pp. 457 - 461.		
	V	Assenmacher, "BSIM 4 Modeling and Parameter Extraction", Jan. 2003, Infineon Technologies AG, Presentation View Graphs, pp. 1 - 23.		
	w	Xi et al., "BSIM4.5.0 Enhancements", Jun. 2005, University of California-Berkeley, Presentation Vie Graphs, pp. 1 - 9.		
	х	Polishchuk et al., "CMOS Vt-Control Improvement Through Implant Lateral Scatter Elimination", Sept. 2005, IEEE International Symposium on Semiconductor Manufacturing, Paper Digest, pp. 193 - 196.		

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.

Notice of References Cited Application/Control No. 10/708,715 Examiner Sun J. Lin Applicant(s)/Patent Under Reexamination BARD ET AL. Page 2 of 2

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-			
	В	US-			
	С	US-			
	D	US-			
	Ε	US-			
	F	US-			
	G	US-			
	Н	US-			
	1	US-			
	J	US-			
	к	US-			
	L	US-			
	м	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	P					
	Q					
	R					
	S					
	Т					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)					
	U	"BSIM4.5.0. Manual: Chapter 14: Well Proximity Effect Model", 2005, University of California-Berkeley, 14-1 - 14-7.					
	v						
	w						
	x						

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.